FDS4470

FAIRCHILD Semiconductor

40V N-Channel PowerTrench[®] MOSFET

General Description

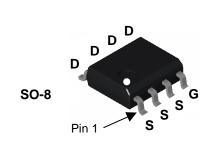
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

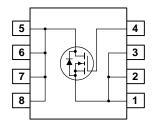
Applications

• DC/DC converter

Features

- 12.5 A, 40 V. $R_{\text{DS(ON)}}$ = 9 m Ω @ V_{GS} = 10 V
- Low gate charge (45 nC)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





125

25

Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		40	V
V _{GSS}	Gate-Source Voltage		+30/-20	V
ID	Drain Current – Continuous	(Note 1a)	12.5	A
	– Pulsed		50	
P _D	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.4	
		(Note 1c)	1.2	
T _J , T _{STG}	Operating and Storage Junction Temperat	ure Range	-55 to +175	°C
Therma	I Characteristics			
R _{AIA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W

R_{0JA} Thermal Resistance, Junction-to-Ambient (Note 1c) R_{0JC} Thermal Resistance, Junction-to-Case (Note 1)

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS4470	FDS4470	13"	12mm	2500 units

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°C/W

°C/W

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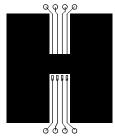
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	Durce Avalanche Ratings (Note 2	2)				
E _{AS}	Drain-Source Avalanche Energy	Single Pulse, V _{DD} =40V, I _D =12.5A			370	mJ
I _{AS}	Drain-Source Avalanche Current				12.5	А
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	40			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C		42		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 32 \text{ V}, V_{\text{GS}} = 0 \text{ V}$			1	μΑ
I _{GSSF}	Gate–Body Leakage, Forward	$V_{\text{GS}} = 30 \text{ V}, V_{\text{DS}} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate–Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 250 \ \mu A$	2	3.9	5	V
$\Delta V_{GS(th)} \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C		-8		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance			6 9	9 14	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$	25			A
g fs	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 12.5 \text{ A}$		45		S
Dvnamio	c Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V},$		2659		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		605		pF
C _{rss}	Reverse Transfer Capacitance	1		298		pF
	g Characteristics (Note 2)		1			
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 20 V, I_D = 1 A,$		14	25	ns
t _r	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		12	22	ns
t _{d(off)}	Turn–Off Delay Time	1		37	59	ns
t _f	Turn–Off Fall Time			29	46	ns
Qg	Total Gate Charge	$V_{DS} = 20 V$, $I_{D} = 12.5 A$,		45	63	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		11.2		nC
Q _{gd}	Gate-Drain Charge	1		11		nC

FDS4470

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-S	ource Diode Characteristics a	Ind Maximum Ratings				
ls	Maximum Continuous Drain-Source Diode Forward Current				2.1	А
V_{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 2.1 A$ (Note 2)		0.7	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = 12.5 \text{ A}, d_{iF}/d_t = 100 \text{ A}/\mu\text{s}$		33		nS
Q _{rr}	Diode Reverse Recovery Charge		1	39		nC

Notes:

1. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



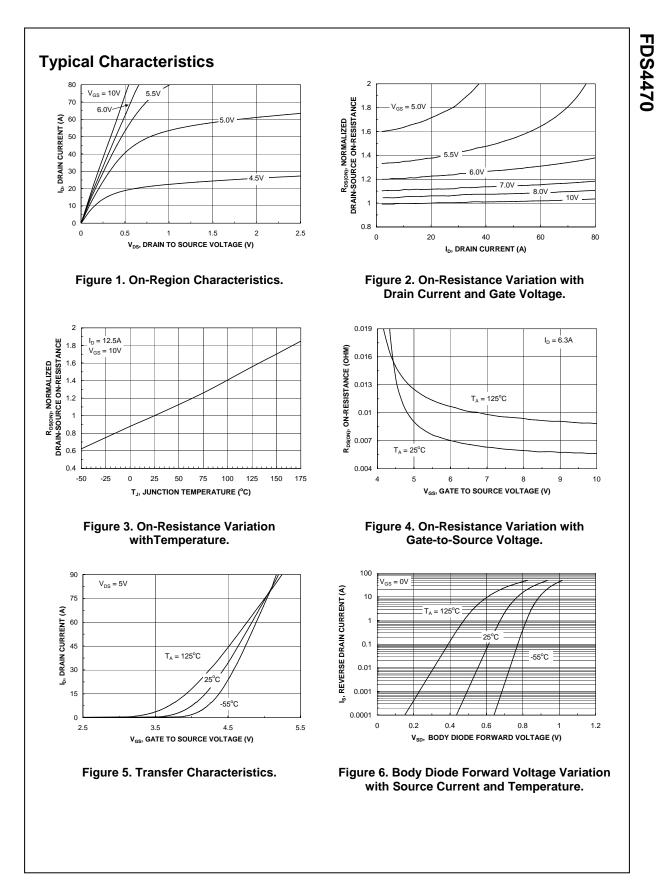




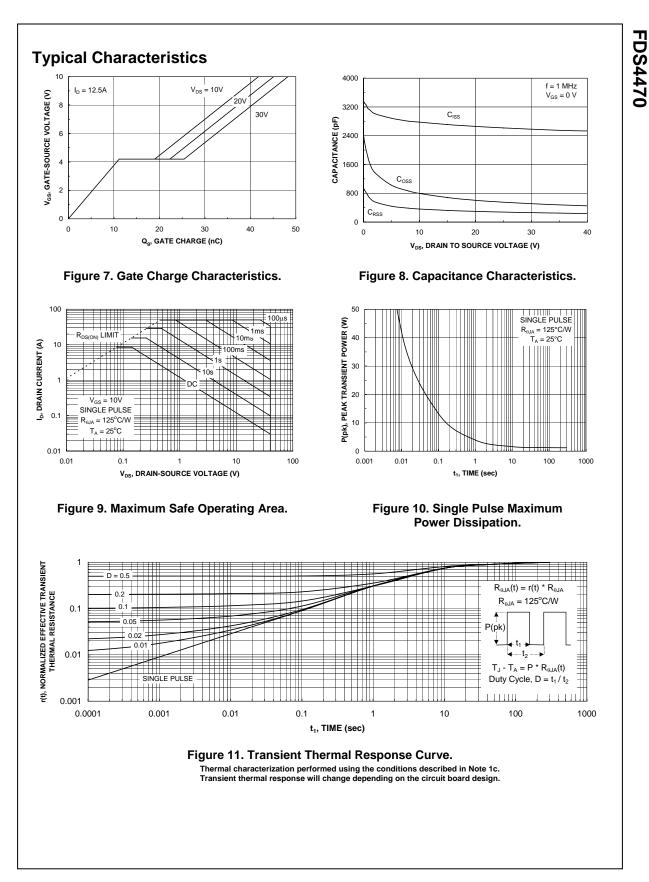
b) 105°C/W when mounted on a .04 in² pad of 2 oz copper c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300μ s, Duty Cycle < 2.0%



FDS4470 Rev D1 (W)



FDS4470 Rev D1 (W)



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Programmable Active Droop™

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